

T491B336M020AH

General Information

Series

T491, Tantalum, MnO2 Tantalum, Commercial Grade, 33 uF, 20%, 20 VDC, SMD, MnO2, Molded, 4 Ohms, 3528, 2.1 mm, 0.8 mm

CATHODE (-) END VIEW



ANODE (+) END VIEW

BOTTOM VIEW E Giue pad shape/design at KEMETS option

SIDE VIEW

MnO2 Tantalum Dielectric Style SMD Chip Description SMD, MnO2, Molded RoHS No Prop 65 WARNING: Cancer and reproductive harm https://www.p65warnings.ca.gov SCIP Number 1dd2e1b8-26dd-4d52-927c-6f9 d519011aa Tin Lead (SnPb) Termination AEC-Q200 No **Typical Component Weight** 107.45 mg Shelf Life 156 Weeks MSL 1

T491

Dimensions	
L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
Н	1.9mm +/-0.2mm
т	0.13mm REF
S	0.8mm +0.1/-0.3mm
F	2.2mm +/-0.1mm
A	1.9mm MIN
В	0.4mm +/-0.15mm
E	2.2mm REF
G	1.8mm REF
Р	0.5mm REF
R	1mm REF
х	0.1mm +/-0.1mm REF

Click here for the 3D model.

Specifications	
Capacitance	33 uF
Tolerance	20%
Voltage DC	20 VDC (85C), 13.4 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	10% 120Hz 25C
Failure Rate	N/A
ESR	4 Ohms (100kHz 25C)
Ripple Current	146 mA (rms, 100kHz 25C), 131.4 mA (rms, 85C), 58.4 mA (rms, 125C)
Leakage Current	6.6 uA (5min 25°C)

Packaging Specifications Packaging T&R, 178mm

Packaging Quantity	2000

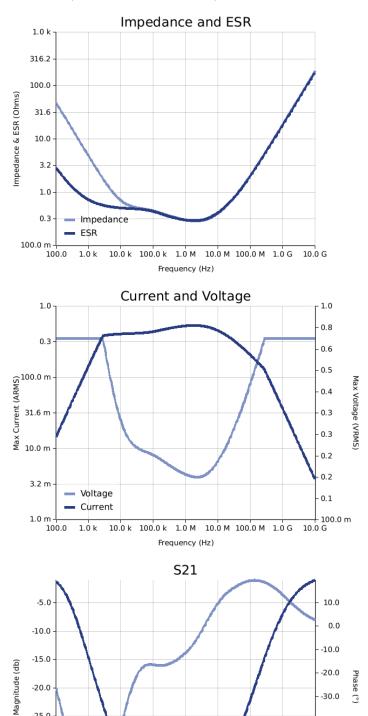
Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.



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Simulations

For the complete simulation environment please visit K-SIM.



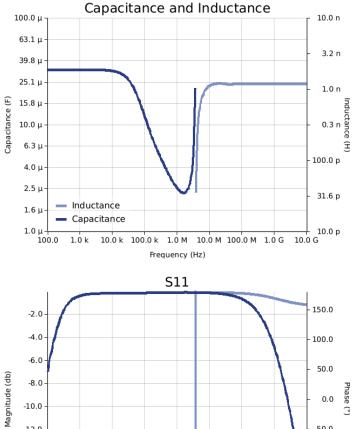
-30.0

-40.0 -50.0

-60.0

-70.0

1.0 M 10.0 M 100.0 M 1.0 G 10.0 G



-50.0 -12.0 -14.0 -100.0 -16.0 S11 Phase -150.0 S11 Magnitude -18.0 100.0 1.0 k 10.0 k 100.0 k 1.0 M 10.0 M 100.0 M 1.0 G 10.0 G

Frequency (Hz)

100.0

S21 Phase

1.0 k

S21 Magnitude

10.0 k 100.0 k

Frequency (Hz)

-25.0

-30.0

-35.0



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These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.

- The ESR used for http:// Ripple Current/ voltage vs. requertly plots is the ESR at an other temperature.
 The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
 The effects shown herein are based on measured data from a multiple part sample of the parts in question.
 Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.
 The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages
- generated at any other harmonics.
 Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.